



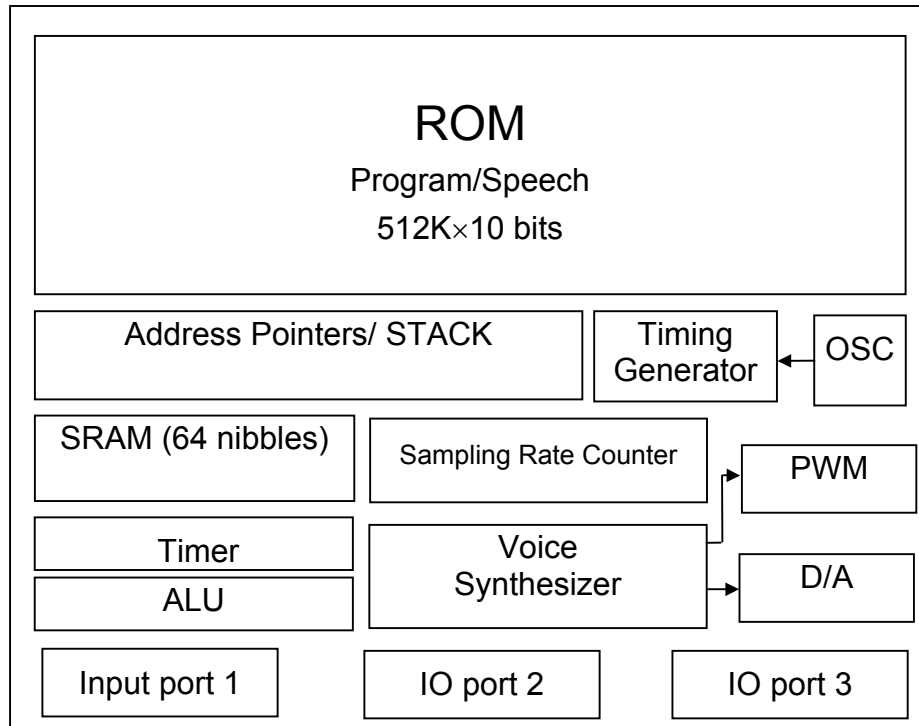
1 INTRODUCTION

SNC11E is a one-channel voice synthesizer IC with PWM direct drive circuit. It built-in a 4-bit tiny controller with one 4-bit input port, two 4-bit I/O ports. By programming through the tiny controller in SNC11E, user's varied applications including voice section combination, key trigger arrangement, output control, and other logic functions can be easily implemented.

2 FEATURES

- ◆ Single power supply 2.4V – 5.5V
- ◆ 168 seconds voice capacity are provided(@6KHZ sample rate)
- ◆ Built in a 4-bit tiny controller
- ◆ One 4-bit input port, two 4-bit I/O ports are provided
- ◆ 64*4 bits RAM are provided
- ◆ 512K*10 ROM size are provided for voice data and program
- ◆ Maximum 16k program ROM is provided
- ◆ Built in a high quality speech synthesizer
- ◆ Adaptive playing speed from 2.5k-20kHz is provided
- ◆ One voice channel
- ◆ Built in a PWM Direct Drive circuit and a fixed current D/A output
- ◆ System clock : 2MHz
- ◆ Low Power Reset

3 Block Diagram



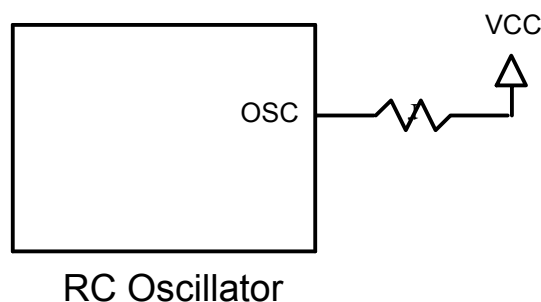
4 PIN ASSIGNMENT

Symbol	I/O	Function Description
P13 ~ P10	I	Bit3 ~ Bit0 of Input port 1
P23 ~ P20	I/O	Bit3 ~ Bit0 of I/O port 2
P33 ~ P30	I/O	Bit3 ~ Bit0 of I/O port 3
VDD	P	Positive power supply
GND	P	Negative power supply
RST	I	Reset pin (active high)
OSC	I	Oscillator Input
BUO1/VO	O	Positive Output of PWM or DA output
BUO2	O	Negative Output of PWM

5 FUNCTION DESCRIPTIONS

5.1. Oscillator

SNC11E accepts RC type oscillator for system clock. The typical circuit diagram for oscillator is listed as follows.



5.2. ROM

SNC11E contains substantial 512K word (10-bit) internal ROM. Program, voices and other data are shared with this same 512K word ROM.

5.3. RAM

SNC11E contains 64 nibble RAM. The 64 nibble RAM is divided into four pages (page 0 to page 3, 16 nibble RAM on each page). In our programming structure, users can easily define and locate RAM page in the program. For instance, users can use the instructions, PAGEn (n=0 to 3) to switch and indicate the RAM page. Besides, users can use direct mode, M0 ~ M15 in the data transfer type instructions, to access all 16 nibbles of each page.

5.4. Power Down Mode

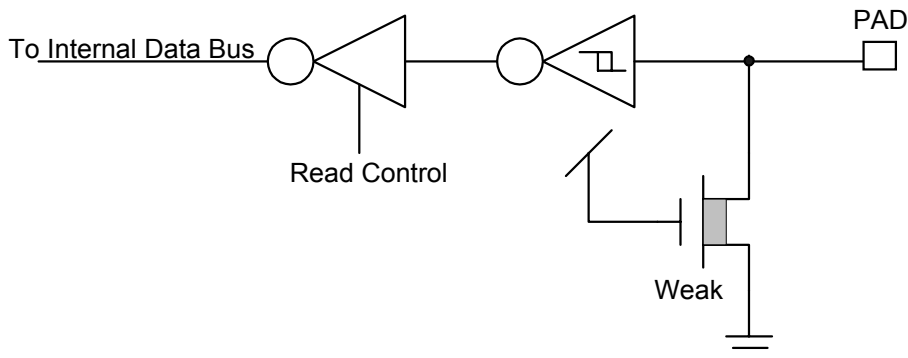
“End” instruction will power down SNC11E and enable IC to consume fewer current for power saving. (<3uA @VDD=3V and <5uA @VDD=5V) Please be aware that when the power down mode is activated in SNC11E, any valid data transition (L→H or H→L) occurring on any input port (P1) or IO ports (P2 and P3) will lead SNC11E back to normal operation mode.

5.5. Sampling Rate Counter

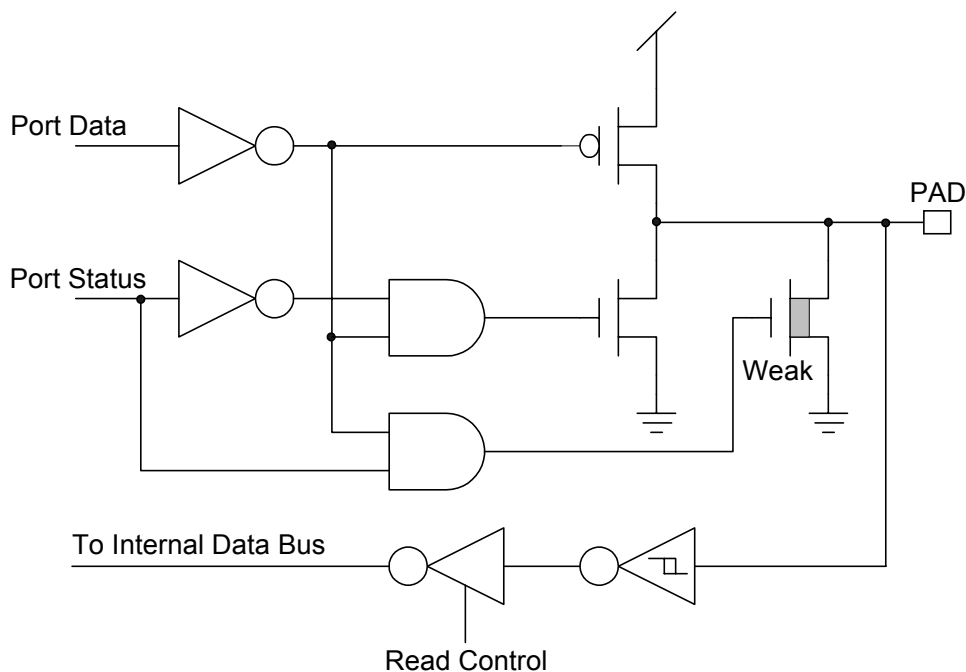
The unique sampling rate counter is designed in voice channel to be able to play diverse voices at different sample playing rates. The playing rate can be adaptively set up among from the wide ranges of 2.5KHz to 20KHz. This feature makes voice close to its original source and yield the better voice quality.

5.6. I/O Ports

P1 is a 4-bit input port, P2 and P3 are two 4-bit I/O ports. Any bit of P2 and P3 can be programmed as either input or output port individually. Any valid data transition (H $\rightarrow$ L or L $\rightarrow$ H) of P1, P2 and P3 can reactivate the chip when the chip is in power-down mode.



Input Port Configuration (P10~P13)



I/O Port Configuration (P20~P23, P30~P33)

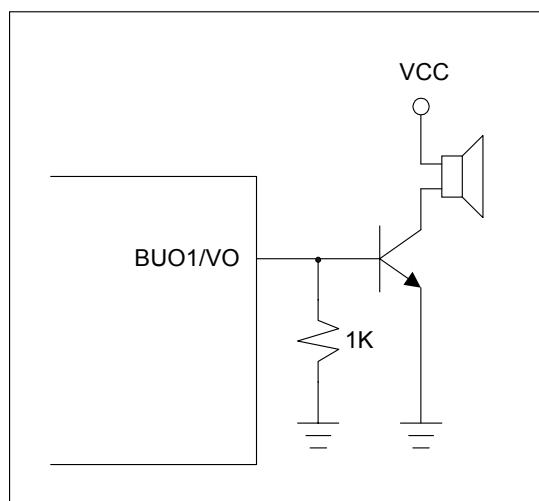
Note: All weak N-MOS's can serve as pull-low resistors.

5.7. DAC & PWM

SNC11E is an advanced chip to be designed having two optimal methods to play out the voices. One is DAC and the other is PWM. Upon user's applications, user can select either DAC or PWM in his design. Please be aware that only one method can be activated at a time.

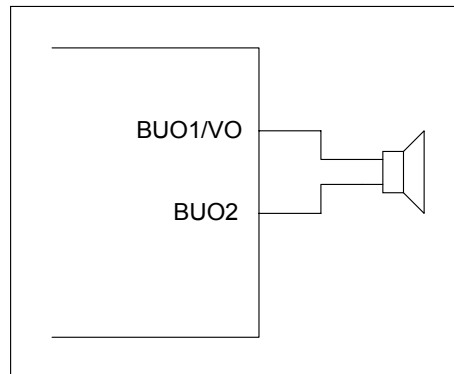
DAC: A 7-bit current type digital-to-analog converter is built-in SNC11E. The relationship between input digital data and output analog current signal is listed in the following table. Also, the recommended application circuit is illustrated as follows.

Input data	Typical value of output current (mA)
0	0
1	3/127
...	
N	$n \cdot (3/127)$
...	
127	3



DAC output

PWM: A PWM (pulse width modulation) circuit is built-in SNC11E. PWM can convert input digital data into pulse trains with suitable different pulse width. The maximum resolution of PWM is 7 bits. Two huge output stage circuits are designed in SNC11E. With this advanced circuit, the chip is capable of driving speaker directly without external transistors. The recommended application circuit is illustrated as follows.



PWM Output



6 ABSOLUTE MAXIMUM RATING

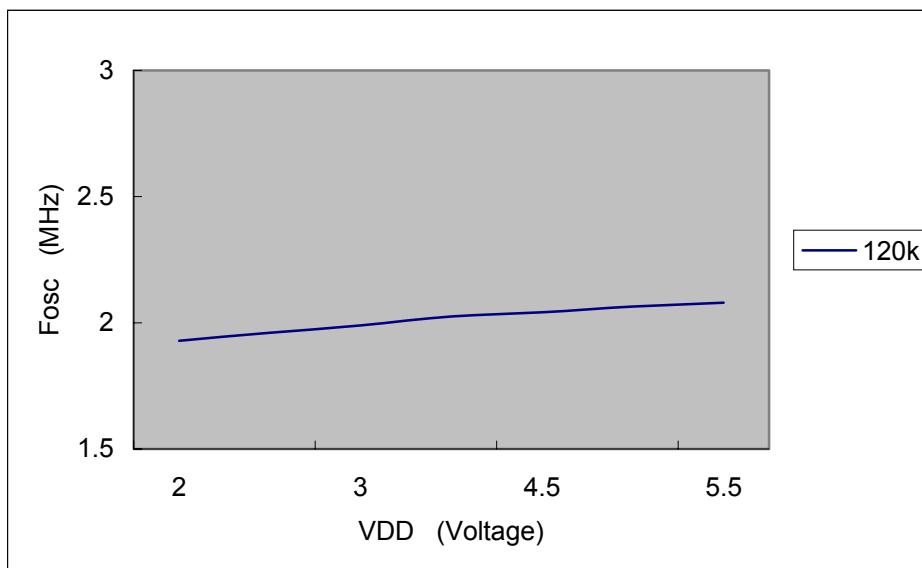
Items	Symbol	Min	Max	Unit.
Supply Voltage	$V_{DD}-V$	-0.3	6.0	V
Input Voltage	V_{IN}	$V_{SS}-0.3$	$V_{DD}+0.3$	V
Operating Temperature	T_{OP}	0	55.0	°C
Storage Temperature	T_{STG}	-55.0	125.0	°C

7 ELECTRICAL CHARACTERISTICS

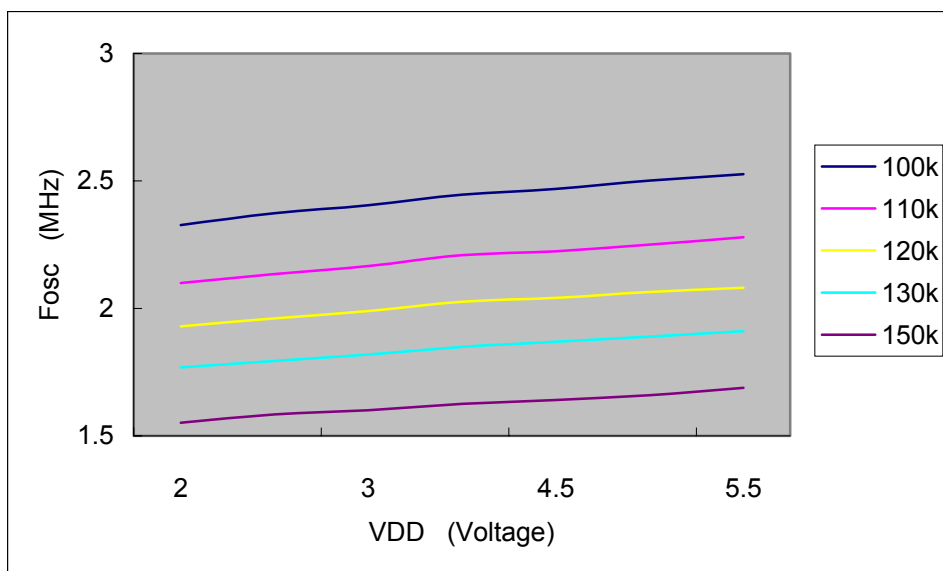
Item	Sym.	Min.	Typ.	Max.	Unit	Condition
Operating Voltage	V_{DD}	2.4	3.0	5.5	V	
Standby current	I_{SBY}	-	2.0 5.0	-	μA	$V_{DD}=3V$, no load $V_{DD}=4.5V$, no load
Operating Current	I_{OPR}	-	300 700	-	μA	$V_{DD}=3V$, no load $V_{DD}=4.5V$, no load
Input current of P1, P2, P3	I_{IH}	-	3.0	10.0	μA	$V_{DD}=3V, V_{IN}=3V$
Drive current of P2, P3	I_{OD}	-	4	-	mA	$V_{DD}=3V, V_O=2.4V$
Sink Current of P2, P3	I_{OS}	-	6	-	mA	$V_{DD}=3V, V_O=0.4V$
Drive current of Buo1	I_{OD}	100	120	-	mA	$V_{DD}=3V, Buo1=1.5V$
Sink Current of Buo1	I_{OS}	100	120	-	mA	$V_{DD}=3V, Buo1=1.5V$
Drive Current of Buo2	I_{OD}	100	120	-	mA	$V_{DD}=3V, Buo2=1.5V$
Sink Current of Buo2	I_{OS}	100	120	-	mA	$V_{DD}=3V, Buo2=1.5V$
Oscillation Freq.	F_{OSC}	-	2.0	-	MHz	$V_{DD}=3V$

8 FOSC Performance

ROSC frequency vs VDD (Typical value, $R=120K\Omega$)

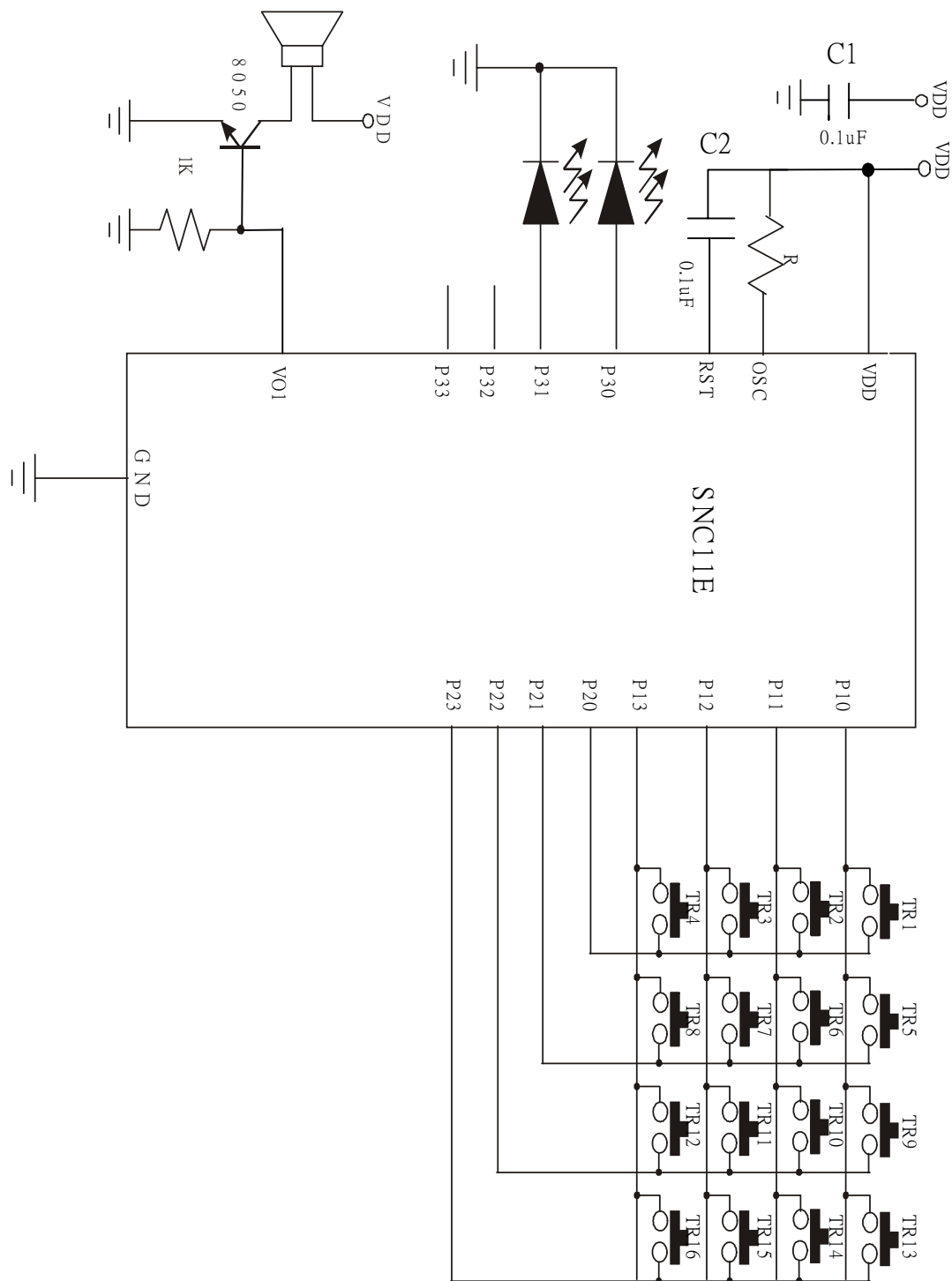


ROSC frequency vs. VDD (For various R)



9 APPLICATION CIRCUIT

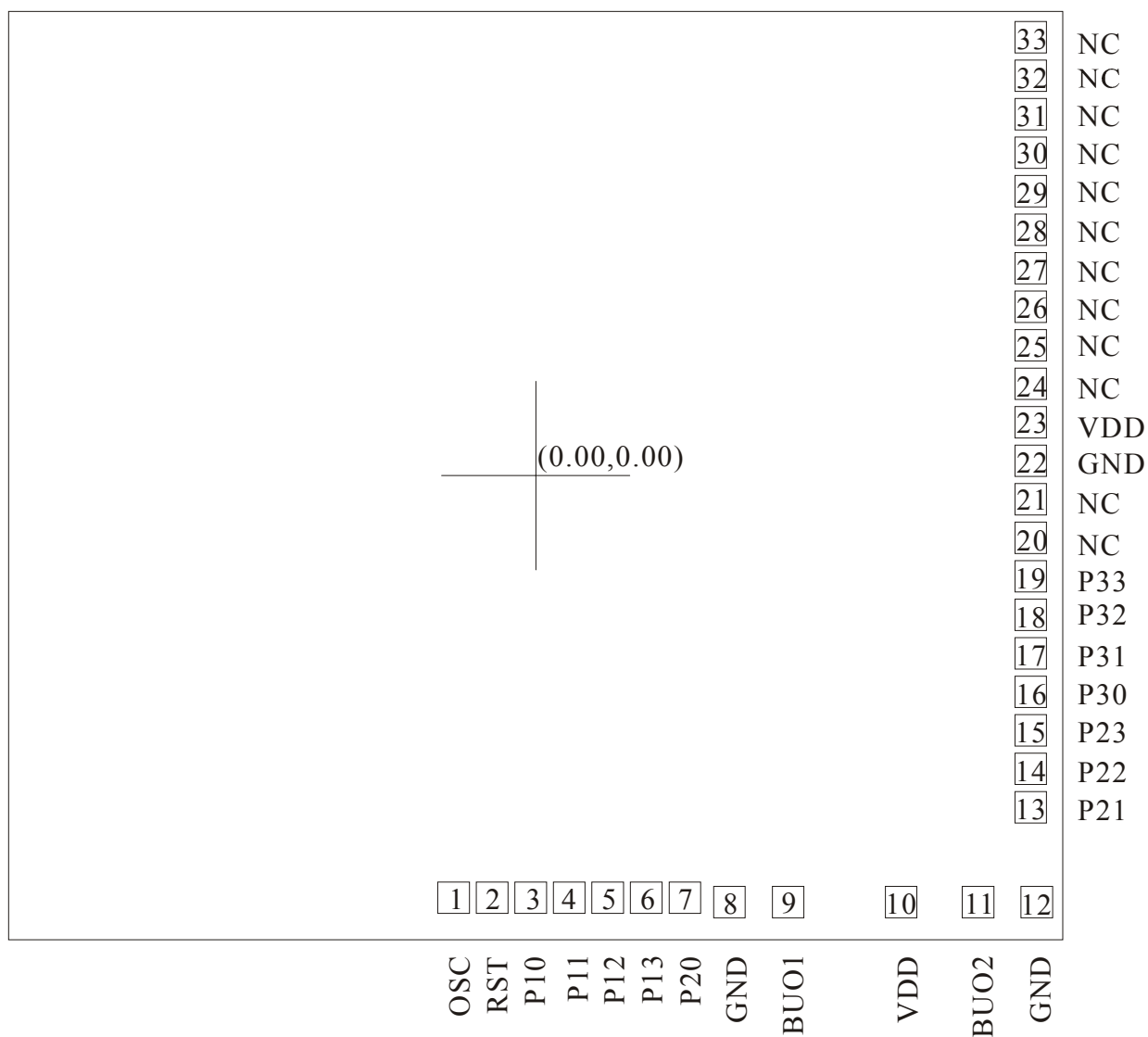
D/A Speaker Output
16 Scan Keys



Note: The C1 (0.1uF) between Power and GND should be closed to VDD pin of SNC11E as possible.



10 BONDING PAD



Note: The substrate MUST be connected to Vss in PCB layout.



DISCLAIMER

The information appearing in SONiX web pages ("this publication") is believed to be accurate.

However, this publication could contain technical inaccuracies or typographical errors. The reader should not assume that this publication is error-free or that it will be suitable for any particular purpose. SONiX makes no warranty, express, statutory implied or by description in this publication or other documents which are referenced by or linked to this publication. In no event shall SONiX be liable for any special, incidental, indirect or consequential damages of any kind, or any damages whatsoever, including, without limitation, those resulting from loss of use, data or profits, whether or not advised of the possibility of damage, and on any theory of liability, arising out of or in connection with the use or performance of this publication or other documents which are referenced by or linked to this publication.

This publication was developed for products offered in Taiwan. SONiX may not offer the products discussed in this document in other countries. Information is subject to change without notice. Please contact SONiX or its local representative for information on offerings available. Integrated circuits sold by SONiX are covered by the warranty and patent indemnification provisions stipulated in the terms of sale only. The application circuits illustrated in this document are for reference purposes only. SONiX DISCLAIMS ALL WARRANTIES, INCLUDING THE WARRANTY OF MERCHANTABILITY OR FITNESS FOR ANY PURPOSE. SONiX reserves the right to halt production or alter the specifications and prices, and discontinue marketing the Products listed at any time without notice. Accordingly, the reader is cautioned to verify that the data sheets and other information in this publication are current before placing orders.

Products described herein are intended for use in normal commercial applications. Applications involving unusual environmental or reliability requirements, e.g. military equipment or medical life support equipment, are specifically not recommended without additional processing by SONiX for such application.